

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

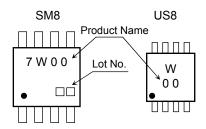
# TC7W00FU, TC7W00FK

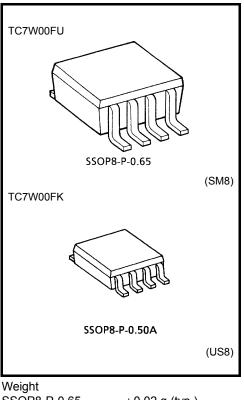
Dual 2-Input NAND Gate

#### Features

- High Speed
- Low power dissipation
- High noise immunity
- :  $t_{pd}$  = 6ns (typ.) at V<sub>CC</sub> = 5V :  $I_{CC}$  = 1µA (max) at Ta = 25°C
- $100 1\mu A (11ax) at 1a$
- :  $V_{\text{NIH}} = V_{\text{NIL}} = 28\% V_{\text{CC}}$  (min)
- Output drive capability : 10 LSTTL Loads
- Symmetrical Output Impedance :  $|I_{OH}| = I_{OL} = 4mA$  (min)
- Balanced propagation delays  $: t_{pLH} \doteq t_{pHL}$
- Wide operating voltage range : V<sub>CC</sub> = 2 to 6 V

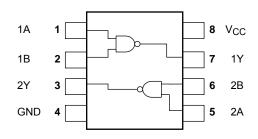






# Weight SSOP8-P-0.65 : 0.02 g (typ.) SSOP8-P-0.50A : 0.01 g (typ.)

# Pin Assignment (top view)



# Absolute Maximum Ratings (Ta = 25°C)

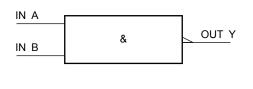
| Characteristics                    | Symbol           | Rating                        | Unit |  |
|------------------------------------|------------------|-------------------------------|------|--|
| Supply voltage                     | V <sub>CC</sub>  | –0.5 to 7.0                   | V    |  |
| DC input voltage                   | V <sub>IN</sub>  | –0.5 to V <sub>CC</sub> + 0.5 | V    |  |
| DC output voltage                  | V <sub>OUT</sub> | –0.5 to V <sub>CC</sub> + 0.5 | V    |  |
| Input diode current                | lıк              | ±20                           | mA   |  |
| Output diode current               | I <sub>OK</sub>  | ±20                           | mA   |  |
| DC output current                  | IOUT             | ±25                           | mA   |  |
| DC V <sub>CC</sub> /ground current | Icc              | ±25                           | mA   |  |
| Power dissipation                  | D-               | 300 (SM8)                     | m)// |  |
|                                    | PD               | 200 (US8)                     | mW   |  |
| Storage temperature                | T <sub>stg</sub> | –65 to 150                    | °C   |  |
| Lead temperature (10 s)            | TL               | 260                           | °C   |  |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

**Truth Table** 

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

# **IEC Logic Symbol**



| А | В | Y |
|---|---|---|
| L | L | Н |
| L | Н | Н |
| Н | L | Н |
| Н | Н | L |

# **Operating Ranges**

| Characteristics          | Symbol                          | Rating                               | Unit |
|--------------------------|---------------------------------|--------------------------------------|------|
| Supply voltage           | V <sub>CC</sub>                 | 2.0 to 6.0                           | V    |
| Input voltage            | V <sub>IN</sub>                 | 0 to V <sub>CC</sub>                 | V    |
| Output voltage           | V <sub>OUT</sub>                | 0 to V <sub>CC</sub>                 | V    |
| Operating temperature    | T <sub>opr</sub>                | -40 to 85                            | °C   |
| Input rise and fall time |                                 | 0 to 1000 $(V_{CC} = 2.0 \text{ V})$ |      |
|                          | t <sub>r</sub> , t <sub>f</sub> | 0 to 500 $(V_{CC} = 4.5 V)$          | ns   |
|                          |                                 | 0 to 400 $(V_{CC} = 6.0 \text{ V})$  |      |

# **Electrical Characteristics**

#### **DC Characteristics**

| Characteristics Symbol Test Condition |                 | Condition                         |                           | Ta = 25°C |      |      | Ta = -40 to 85°C |      | Unit |    |
|---------------------------------------|-----------------|-----------------------------------|---------------------------|-----------|------|------|------------------|------|------|----|
|                                       |                 | $V_{CC}(V)$                       | Min                       | Тур.      | Max  | Min  | Max              | Unit |      |    |
|                                       |                 | VIH —                             |                           | 2.0       | 1.5  | _    | _                | 1.5  | _    |    |
| High-level input voltage VI           | VIH             |                                   |                           | 4.5       | 3.15 | _    | _                | 3.15 | _    |    |
|                                       |                 |                                   |                           | 6.0       | 4.2  | _    |                  | 4.2  | _    | V  |
|                                       |                 |                                   |                           | 2.0       |      | _    | 0.5              | _    | 0.5  | V  |
| Low-level input voltage V             | $V_{\text{IL}}$ |                                   | _                         | 4.5       |      | _    | 1.35             | _    | 1.35 |    |
|                                       |                 |                                   |                           | 6.0       |      | _    | 1.8              | _    | 1.8  |    |
| High-level output voltage             |                 | VIN = VIH<br>or VIL               | I <sub>OH</sub> = -20 μA  | 2.0       | 1.9  | 2.0  | _                | 1.9  | _    | V  |
|                                       |                 |                                   |                           | 4.5       | 4.4  | 4.5  | _                | 4.4  | _    |    |
|                                       | V <sub>OH</sub> |                                   |                           | 6.0       | 5.9  | 6.0  | _                | 5.9  | _    |    |
|                                       |                 |                                   | I <sub>OH</sub> = -4 mA   | 4.5       | 4.18 | 4.31 | _                | 4.13 | _    |    |
|                                       |                 |                                   | I <sub>OH</sub> = -5.2 mA | 6.0       | 5.68 | 5.80 | _                | 5.63 | —    |    |
|                                       |                 | V <sub>IN</sub> = V <sub>IH</sub> | I <sub>OL</sub> = 20 μΑ   | 2.0       |      | 0.0  | 0.1              | _    | 0.1  | v  |
| Low-level output voltage              |                 |                                   |                           | 4.5       | _    | 0.0  | 0.1              | _    | 0.1  |    |
|                                       | V <sub>OL</sub> |                                   |                           | 6.0       | _    | 0.0  | 0.1              | _    | 0.1  |    |
|                                       |                 |                                   | I <sub>OL</sub> = 4 mA    | 4.5       | _    | 0.17 | 0.26             | _    | 0.33 |    |
|                                       |                 |                                   | I <sub>OL</sub> = 5.2 mA  | 6.0       |      | 0.18 | 0.26             | _    | 0.33 |    |
| Input leakage current                 | I <sub>IN</sub> | $V_{IN} = V_{CC}$ or GND          |                           | 6.0       |      |      | ±0.1             |      | ±1.0 | μA |
| Quiescent supply current              | ICC             | $V_{IN} = V_{CC}$                 | or GND                    | 6.0       | _    |      | 1.0              | _    | 10.0 | μA |

# AC Characteristics ( $C_L$ = 15pF, $V_{CC}$ = 5V, Ta = 25°C)

| Characteristics        | Symbol                               | Test Condition | -   | Unit |     |       |
|------------------------|--------------------------------------|----------------|-----|------|-----|-------|
|                        | Symbol                               |                | Min | Тур. | Max | Offic |
| Output Transition Time | t <sub>TLH</sub><br>t <sub>THL</sub> | _              |     | 4    | 8   | ns    |
| Propagation Delay Time | <sup>t</sup> pLH<br><sup>t</sup> pHL | _              | _   | 6    | 12  | ns    |

# AC Characteristics ( $C_L$ = 50pF, Input: $t_r = t_f = 6$ ns)

| Characteristics               | Symbol                               | Test Condition |                     | Ta = 25°C |      |     | Ta = -40 to 85°C |     | Unit  |
|-------------------------------|--------------------------------------|----------------|---------------------|-----------|------|-----|------------------|-----|-------|
|                               |                                      |                | V <sub>CC</sub> (V) | Min       | Тур. | Max | Min              | Max | Offic |
| Output Transition Time        | <b>4</b>                             | _              | 2.0                 | _         | 25   | 75  | _                | 95  |       |
|                               | t <sub>тLH</sub><br>t <sub>тHL</sub> |                | 4.5                 | _         | 7    | 15  | _                | 19  | ns    |
|                               | THL                                  |                | 6.0                 | _         | 6    | 13  | —                | 16  |       |
| Propagation delay time        | t <sub>pLH</sub><br>t <sub>pHL</sub> | _              | 2.0                 | _         | 25   | 75  | —                | 95  |       |
|                               |                                      |                | 4.5                 | _         | 9    | 15  | —                | 19  | ns    |
|                               |                                      |                | 6.0                 | _         | 8    | 13  | —                | 16  |       |
| Input capacitance             | C <sub>IN</sub>                      |                |                     | _         | 5    | 10  | _                | 10  | pF    |
| Power dissipation capacitance | C <sub>PD</sub>                      |                | (Note 1)            | _         | 20   | _   | _                | _   | pF    |

Note 1: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

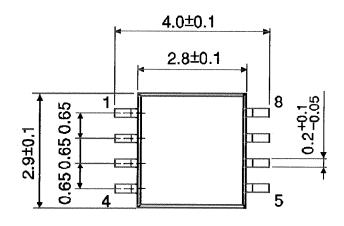
Average operating current can be obtained by the equation:  $I_{CC\ (opr)}=C_{PD}\cdot V_{CC}\cdot f_{IN}+I_{CC}/2$ 

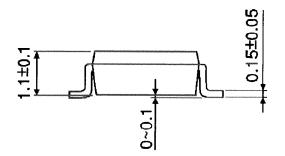
# **TOSHIBA**

# Package Dimensions

SSOP8-P-0.65

Unit : mm





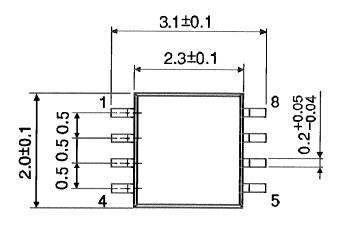
Weight: 0.02 g (typ.)

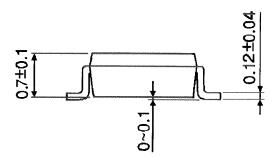
# <u>TOSHIBA</u>

# Package Dimensions

SSOP8-P-0.50A

Unit : mm





Weight: 0.01 g (typ.)

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